Diode Pumped Sub-Nanosecond Passively Q-Switched Laser

MPL1510

FEATURES

- > More than 2 mJ pulse energy at 1064 nm
- > Short pulse duration < 500 ps
- > 100 Hz repetition rate
- > Ultra-compact
- Passively Q-switched
- Average power 200 mW
- > High peak power 4 MW
- > Guaranteed > 3 Gshot lifetime
- Other wavelengths (e.g. 1053 nm, 1342 nm, 671 nm, 447 nm) are available

APPLICATIONS

- Laser-induced breakdown spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- Ignition of gas mixtures

MPL1510 series DPSS passively

Q-switched sub-nanosecond lasers deliver high peak powers > 4 MW at 100 Hz repetition rate. Short laser cavity is fixed on thermostabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Subnanosecond pulse duration of < 500 ps, high pulse energy more than 2 mJ, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 2 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.







Specifications 1)

MODEL	MPL2510	MPL1510		
Pulse energy	·			
at 1064 nm	2 mJ	1 mJ		
at 532 nm	1 mJ	0.5 mJ		
at 355 nm	0.5 mJ	0.25 mJ		
at 266 nm	0.25 mJ	0.15 mJ		
Typical pulse duration	< 500	< 500 ps ²⁾		
Pulse to pulse energy stability (RMS)				
at 1064 nm	< 1	< 1 % ³⁾		
at 532 nm	< 2.0	< 2.0 % ³⁾		
at 355 nm	< 3.0	< 3.0 % ³⁾		
at 266 nm	< 4.0	< 4.0 % ³⁾		
Power drift	± 3.0	± 3.0 % ⁴⁾		
Pulse repetition rate 5)	1 – 1	1 – 100 Hz		
Beam profile	close to	close to Gaussian		
Beam divergence 6)	< 6 r	< 6 mrad		
Polarization	linear, horizon	linear, horizontal at 1064 nm		
Spectral linewidth	SL	SLM		
Beam pointing stability 7)	< 10	< 10 µrad		
Typical beam diameter 8)	1.5	1.5 mm		
Jitter	~ 2 µs	~ 2 µs RMS ⁹⁾		

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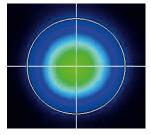
Loor bood (Myl yl I)	138 × 164 × 48.5 mm		
Laser head (W×L×H)	113 × 162.5 × 45.5 mm (OEM version)		
O / W -)	257 × 271 × 153 mm		
Controller unit (W×L×H)	75 × 200 × 70 mm (OEM version)		

OPERATING REQUIREMENTS

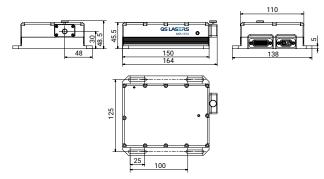
Cooling requirements	Air cooled		
Ambient temperature	15 – 30 °C		
Relative humidity (non-condensing)	10 - 80 %		
Mains voltage	100 – 230 VAC, single phase, 50 – 60 Hz ¹⁰⁾		
Power consumption	< 20 W	< 10 W	

- Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- 2) FWHM level at 1064 nm. Shorter pulse duration (< 350 ps, <200 ps) is available by request. Please inquire for detailed specifications.
- ³⁾ Averaged from 60 seconds time interval in 5 series.
- 4) Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 100 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- 6) Full angle measured at the 1/e² level. Lower beam divergence is available upon request, please inquire for more details.
- 7) RMS value measured from 1000 shots.
- Beam diameter is measured 20 cm from laser output at the 1/e² level.
- ⁹⁾ In respect to Q-switch triggering rising edge pulse.
- Laser can be powered from appropriate 12 VDC power source. Inquire for details.

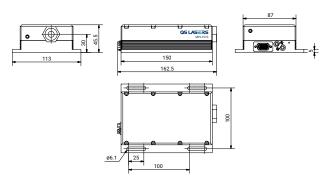




Typical beam intensity profile (20 cm from laser output) of MPL1510 series lasers



MPL1510 series laser head dimensions (in mm)



MPL1510 series laser head dimensions OEM version (in mm)